Application Data Sheet

Application Information

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Filing Date::

Application Type:: Regular

Subject Matter:: Utility

Title :: BEAM IRRADIATION

APPARATUS, BEAM

IRRADIATION METHOD,

AND METHOD FOR

MANUFACTURING THIN

FILM TRANSISTOR

Attorney Docket Number:: 0756-7285

Total Drawing Sheets:: 8

Small Entity?:: No

Applicant Information

Applicant Authority Type:: Inventor

Primary Citizenship Country:: Japan

Given Name:: Koichiro

Middle Name::

Family Name:: TANAKA

Name Suffix::

City of Residence:: Atsugi

State or Province of Residence:: Kanagawa

Country of Residence:: Japan

Street of mailing address:: c/o Semiconductor Energy

Laboratory Co., Ltd.

398, Hase

City of mailing address:: Atsugi-shi

State or Province of mailing address:: Kanagawa-ken

Country of mailing address:: Japan

Postal or Zip Code of mailing address:: 243-0036

Correspondence Information

Correspondence Customer Number :: 31780

E-Mail address:: erobinson@riplo.com

Representative Information

Representative Customer Number:: 31780

Domestic Priority Information

Application ::	Continuity Type::	Parent Application::	Parent Filing Date::

Foreign Priority Information

Country::	Application number::	Filing Date::	Priority Claimed::
Japan	2003-116408	04/21/2003	Yes

Assignee Information

Assignee name:: Semiconductor Energy

Laboratory Co., Ltd.

Street of mailing address:: 398, Hase

City of mailing address:: Atsugi-shi

State or Province of mailing address:: Kanagawa-ken

Country of mailing address:: Japan

Postal or Zip Code of mailing address:: 243-0036